MSKSEMI 美森科













ESD

1/5

TSS

MOV

GDT

PIFD

AZ1345-04F-MS

Product specification





Features

- Protects two or four I/O lines
- Low capacitance: 0.5pF Typical between I/O channel
- Low leakage current
- 5V operating voltage
- Response time < 1ns
- Solid-state silicon avalanche technology
- Device meets MSL 1 requirements
- RoHS compliant

Applications

- High Definition Multi-Media Interface (HDMI)
- Digital Visual Interface (DVI)
- USB 1.1/2.0/3.0/OTG
- IEEE 1394 Firewire Ports
- Notebooks & Handhelds
- Projection TV & Monitors
- Set-top box
- Flat Panel Displays
- PCI Express

Mechanical Characteristics

- DFN2510 package
- Flammability Rating: UL 94V-0
- Terminal: Matte tin plated.
- Packaging: Tape and Reel
- High temperature soldering guaranted:260 ℃/10s
- Reel size: 7 inch

Reference News

PACKAGE OUTLINE	Pin Configuration	Marking
	1 2 3 4 5 4 5 4 4 5 4 4 5 6	.104VH
DFN2510		



Maximum Ratings And Characteristics @ 25°C Ambient Temperature (unless otherwise noted)

Symbol	Parameter	Value	Units
P _{PP} Peak Pulse Power (8/20µs)		150	W
I _{PP} Peak Pulse Current (8/20μs)		5	Α
.,	ESD per IEC 61000-4-2 (Air) ±15		_
V _{ESD}	ESD per IEC 61000-4-2 (Contact)	±8	kV
T _{OPT} Operating Temperature		-55/+150	$^{\circ}$
T _{STG} Storage Temperature		-55/+150	$^{\circ}$

Electrical Characteristics(Tamb=25℃)

Symbol	Parameter	Test Condition	Min	Тур	Max	Units
V _{RWM}	Reverse Working Voltage	Any I/O pin to GND			5.0	V
V _{BR}	Reverse Breakdown Voltage	$I_T = 1mA$ Any I/O pin to GND	6.0			V
I _R	Reverse Leakage Current	V _{RWM} = 5V Any I/O pin to GND			1	uA
VF	Diode Forward Voltage	I _F = 15mA		0.85	1.2	V
V _{C1}	Clamping Voltage 1	I_{PP} = 1A, t_p = 8/20 μ s Any I/O pin to GND			15.5	V
V _{C2}	Clamping Voltage 2	I_{PP} = 5, t_p = 8/20µs Any I/O pin to GND			25	V
C _{J1}	Junction Capacitance 1	V _R = 0V, f = 1MHz Between I/O pins		0.3	0.6	pF
C _{J2}	Junction Capacitance 2	$V_R = 0V$, $f = 1MHz$ Any I/O pin to GND		0.45	0.8	pF

Note: I/O pins are pin 1,2,4,5.



Electrical Characteristics Curve

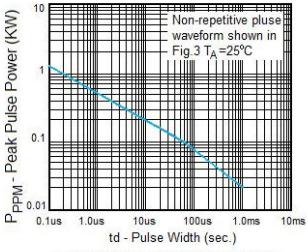
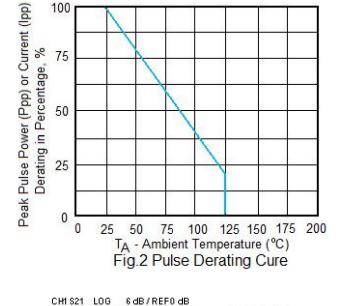


Fig. 1 Peak Pulse Power Rating



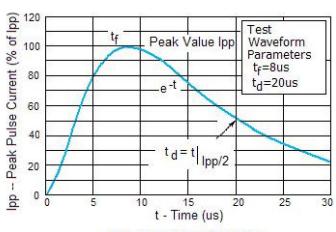


Fig. 3 Pulse Waveform

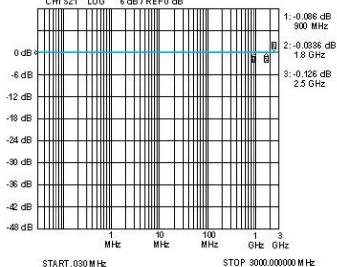
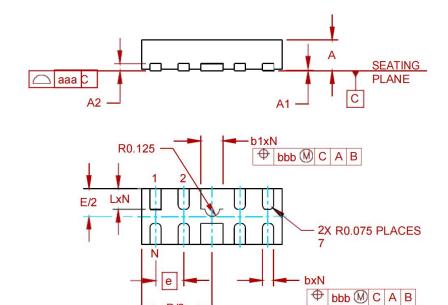
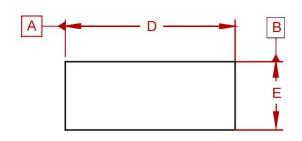


Fig.4 Insertion Loss S21 - I/O to I/O



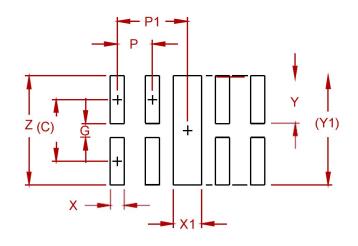
PACKAGE MECHANICAL DATA





	DIMENSI			ONS		
DIM	INCHES		MILLIMETERS			
	MIN	NOM	MAX	MIN	NOM	MAX
Α	.020	.023	.026	0.50	0.58	0.65
A1	0.00	.001	.002	0.00	0.03	0.05
A2	(.005)		(0	. 13)		
b	.006	.008	.010	0. 15	0.20	0.25
1	.014	.016	.018	0.35	0.40	0.45
D	.094	.098	. 102	2.40	2.50	2.60
E	.035	.039	.043	0.90	1.00	1. 10
е	.020 BSC		0.5	0 BSC		
L	.012	.015	.017	0.30	0.38	0.425
N	8			8		
aaa	.003		0.08			
bbb	.004		0. 10			

Suggested Pad Layout



	DIMENSIONS			
DIM	INCHES	MILLIMETERS		
С	(.034)	(0.875)		
G	.008	0.20		
Р	.020	0.50		
P1	.039	1.00		
Χ	.008	0.20		
X1	.016	0.40		
Υ	.027	0.675		
Y1	(.061)	(1.55)		
Z	.061	1.55		

NOTES:

CONTROLLING DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGREES).
THIS LAND PATTERN IS FOR REFERENCE PURPOSES ONLY.
CONSULT YOUR MANUFACTURING GROUP TO ENSURE YOUR
COMPANY'S MANUFACTURING GUIDELINES ARE MET.

REEL SPECIFICATION

P/N	PKG	QTY
AZ1345-04F-MS	DFN2510	3000



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